

CYTY SERIES (InSb) HALL-EFFECT ELEMENTS

CYTY series Hall-effect elements are made of compound semiconductor material indium stibnite (InSb), which utilizes the Hall Effect principle. It can convert a magnetic flux density signal linearly into voltage output.

FEATURES

- High Magnetic Sensitivity
- Low Offset Voltage
- Miniature Package

TYPICAL APPLICATION

- Magnetic Field Measurement
- Current Sensor
- Detection of Speed
- DC Brushless Motor
- Position Control

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Input Current	I_i	20 ($T_A=40^\circ\text{C}$)	mA
Input Voltage	V_i	2 ($T_A=40^\circ\text{C}$)	V
Operating Temperature Range	T_A	-40~110	$^\circ\text{C}$
Storage Temperature Range	T_S	-40~120	$^\circ\text{C}$

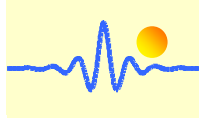
Hall Output Voltage V_H (mV)

Label	Hall Output Voltage
Q	45~60
R	55~75
D	195~230
E	225~275
F	270~320
G	315~370

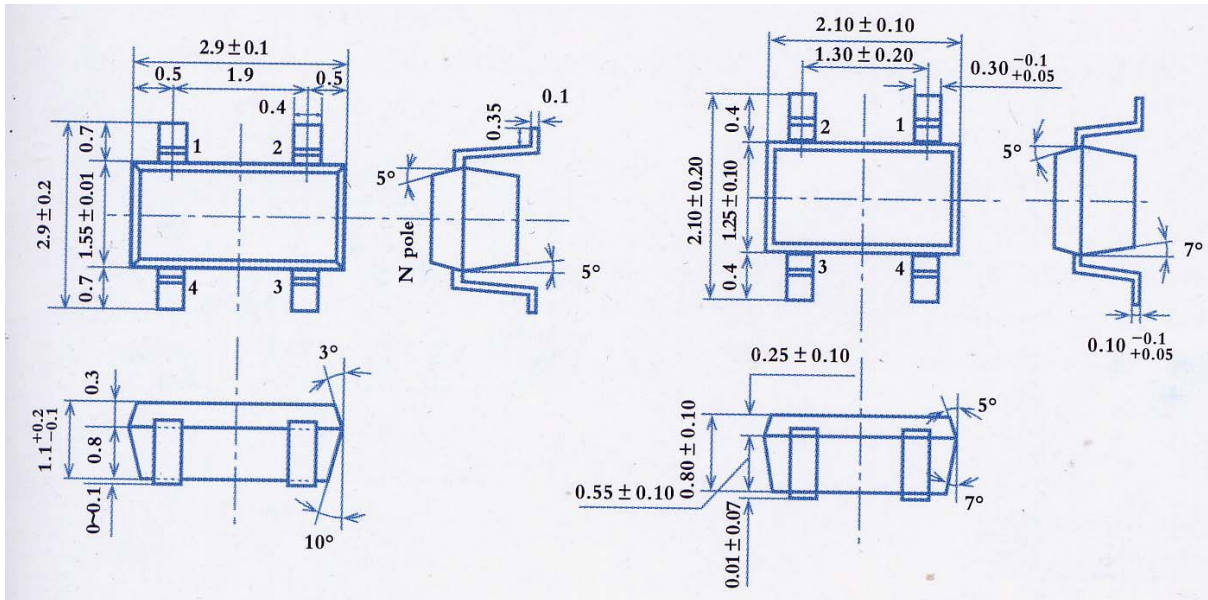
ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Test Condition	Type and Value				
				CYTY211	CYTY108A	CYTY320	CYTY300B-CS
Hall output voltage	V_H (mV)	Constant voltage driven, $V_i=1\text{V}$ $B=50\text{mT}$	Min	45	195	195	195
			Max	75	370	370	370
Offset voltage	V_o (mV)	$B=0$ $V_i=1\text{V}$	Min	-7	-7	-7	-7
			Max	+7	+7	+7	+7
Input resistance	$R_i(\Omega)$	$B=0$ $I_i=0.1\text{mA}$	Min	240	240	240	240
			Max	550	550	550	550
Output resistance	$R_o(\Omega)$	$B=0$ $I_i=0.1\text{mA}$	Min	240	240	240	240
			Max	550	550	550	550
Output voltage temperature coefficient	αV_H (%/°C)	$B=50\text{mT}$ $I_i=5\text{mA}$	Max	-2	-2	-2	-2
Input, Output resistance temperature coefficient	αR_i (%/°C)	$B=0$ $I_i=0.1\text{mA}$					
Isolation resistance	(M Ω)	100V DC		>1.0	>1.0	>1.0	>1.0

- Note:** 1. The Hall output voltage V_H = the effective voltage - V_o
2. The types are different according to the Hall output voltage V_H (mV)

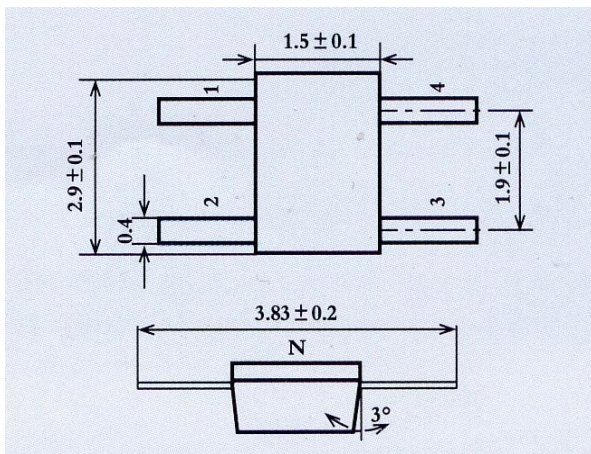


Package Outline Drawing (Unit: mm)

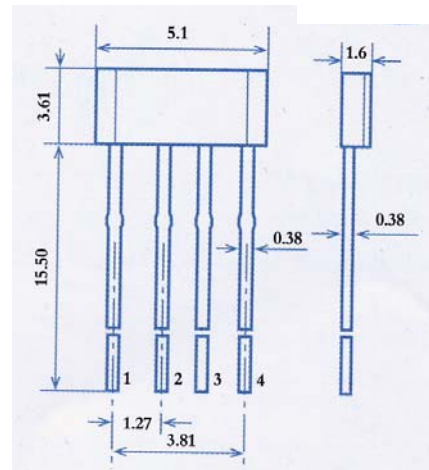


CYTY211 (SOT-143)
2, 4: Input; 1, 3: Output

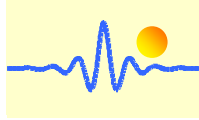
CYTY108A
1, 3: Input; 2, 4: Output



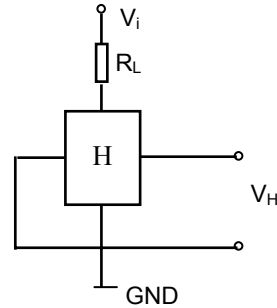
CYTY320 (SOT-143-1)
1, 3: Input; 2, 4: Output



CYTY300B-CS
1, 3: Input; 2, 4: Output

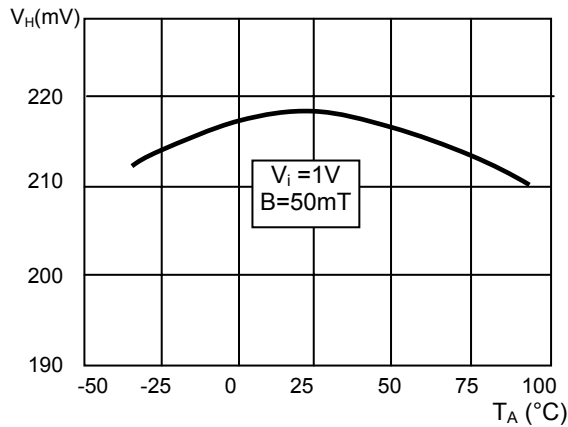


FUNCTIONAL BLOCK DIAGRAM

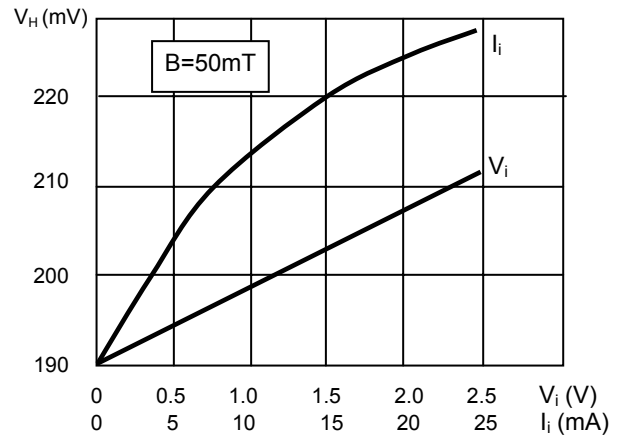


CHARACTERISTICS CURVES

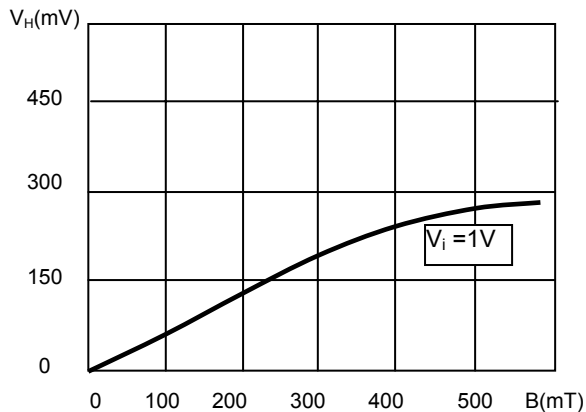
$V_H \sim T_A$ (CYTY320, CYTY108A,
CYTY300B-CS)



$V_H \sim V_i, I_i$ (CYTY320, CYTY108A,
CYTY300B-CS)



$V_H \sim B$ (CYTY211)



$V_H \sim B$ (CYTY320, CYTY300B-CS)

